

Product data sheet

Product profile 1.

1.1 General description

Enhanced ultrafast power diode in a SOD113 (2-lead TO-220F) plastic package.

1.2 Features and benefits

- High thermal cycling performance
- Isolated package
- Low on-state losses

- Low thermal resistance
- Soft recovery characteristic

1.3 Applications

■ Dual Mode (DCM and CCM) PFC

■ Power Factor Correction (PFC) for Interleaved Topology

1.4 Quick reference data

Quick reference data Table 1.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; T _h ≤ 72 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	9	Α
Static cha	racteristics					
V _F	forward voltage	$I_F = 8 \text{ A}$; $T_j = 25 \text{ °C}$; see Figure 5	-	1.45	1.9	V
		$I_F = 8 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.25	1.7	V



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	Α	anode	mb	K
mb	n.c.	mounting base; isolated	SOD113 (TO-220F)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYV29FX-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; δ = 0.5 ; $T_h \le 72$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	9	Α
I _{FRM}	repetitive peak forward current	square-wave pulse; δ = 0.5 ; t_p = 25 μ s; $T_h \le 72$ °C	-	18	Α
I _{FSM}	non-repetitive peak forward current	sine-wave pulse; $t_p = 10 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$; see Figure 3	-	91	Α
		sine-wave pulse; $t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$; see Figure 3	-	100	А
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	150	°C

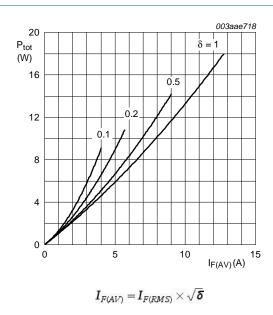


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

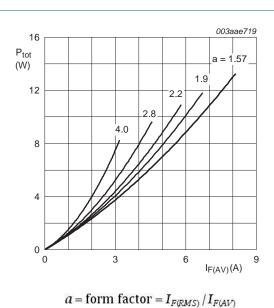


Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

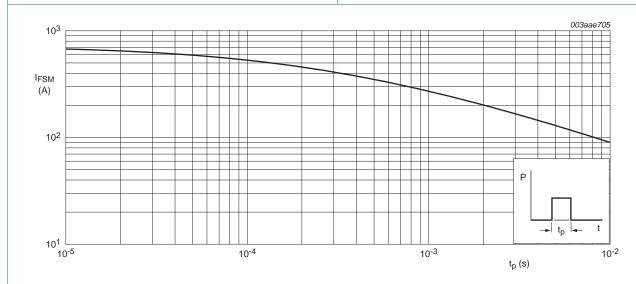


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound ; see Figure 4	-	-	5.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	55	-	K/W

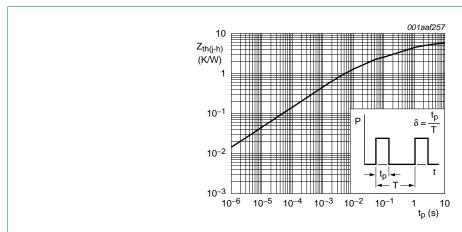


Fig 4. Transient thermal impedance from junction to heatsink as a function of pulse width

6. Isolation characteristics

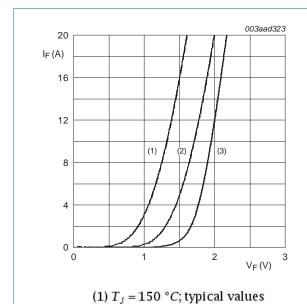
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	f = 1 MHz; from cathode to external heatsink	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static cha	Static characteristics						
V _F	forward voltage	$I_F = 8 \text{ A}$; $T_j = 25 \text{ °C}$; see Figure 5	-	1.45	1.9	V	
		I _F = 8 A; T _j = 150 °C; see <u>Figure 5</u>	-	1.25	1.7	V	
I _R	reverse current	$V_R = 600 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	50	μA	
		V _R = 600 V; T _j = 100 °C	-	-	1.5	mA	
Dynamic o	haracteristics						
Q _r	recovered charge	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/s};$	-	13	-	nC	
t _{rr}	reverse recovery time	T _j = 25 °C; see <u>Figure 6</u>	-	17.5	35	ns	
I _{RM}	peak reverse recovery current		-	1.5	-	Α	
V_{FRM}	forward recovery voltage	I_F = 1 A; dI_F/dt = 100 A/s; T_j = 25 °C; see Figure 7	-	3.2	-	V	



(2) $T_j = 150 \, ^{\circ}C$; maximum values (3) $T_j = 25 \, ^{\circ}C$; maximum values

Fig 5. Forward current as a function of forward voltage

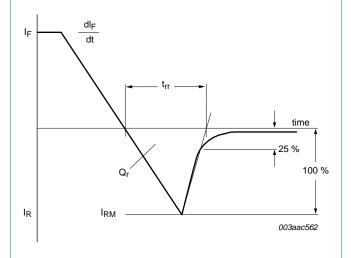
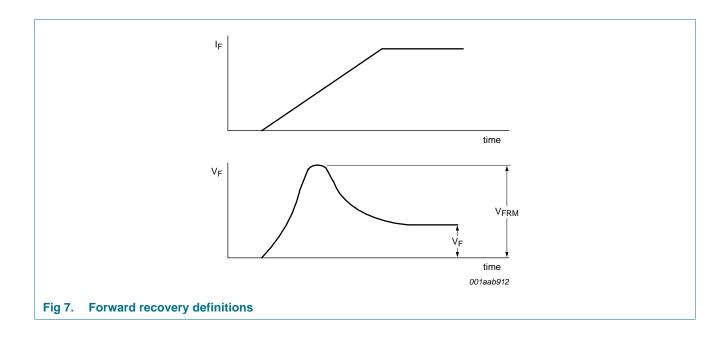


Fig 6. Reverse recovery definitions; ramp recovery



8. Package outline

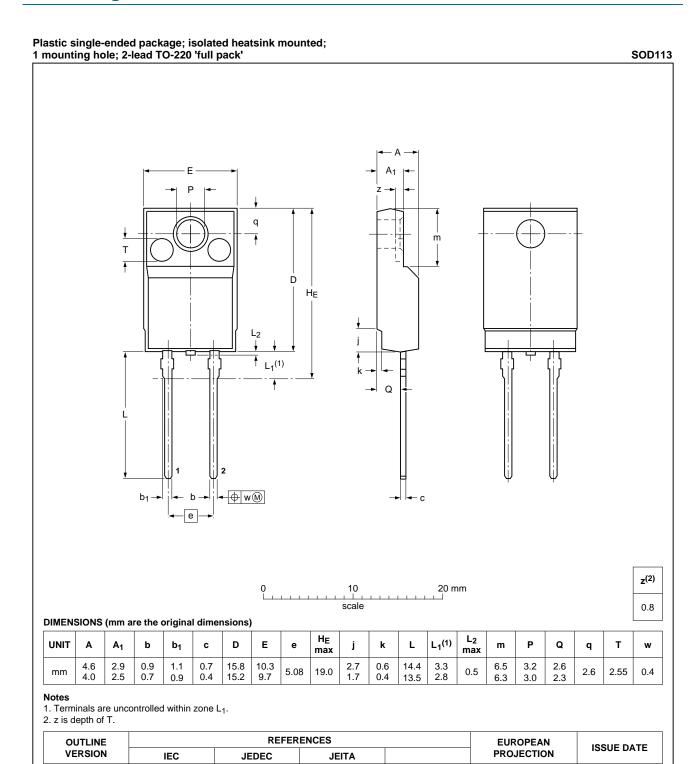


Fig 8. Package outline SOD113 (TO-220F)

BYV29FX-600

Product data sheet

SOD113

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2-lead TO-220F

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9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29FX-600 v.5	20120416	Product data sheet	-	BYV29FX-600 v.4
Modifications:	 Various chang 	es to content.		
BYV29FX-600 v.4	20110307	Product data sheet	-	BYV29FX-600 v.3

10. Legal information

10.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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